Electronic Supplementary Material (ESI) for Journal of Materials Chemistry A.

Supporting Information for

Monolayer titanium carbide hollow spheres arrays formed via atomic layer deposition assisted method and their excellent high-temperature supercapacitor performance

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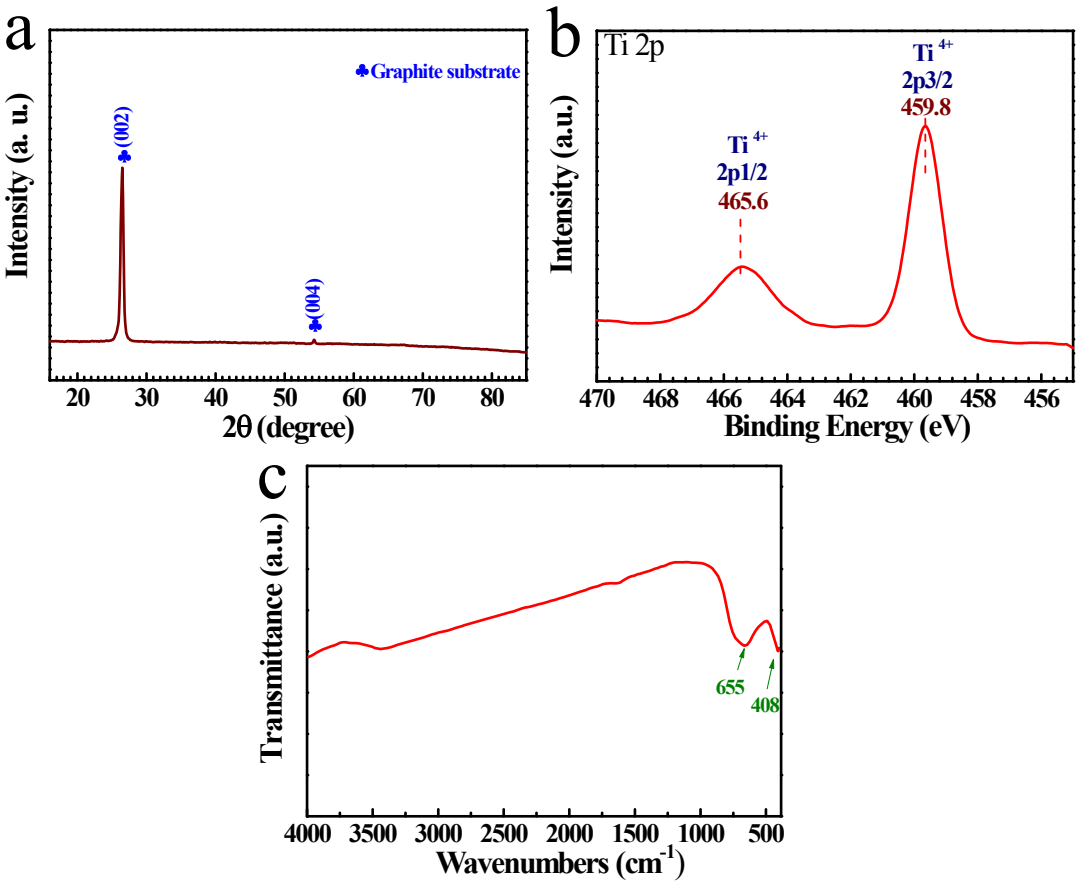

Fig. S1. Structural and morphological characterizations of AlD-TiO_2 monolayer sphere arrays: (a) XRD pattern; (b) XPS analysis: Ti 2p spectrum; (c) FTIR spectrum.

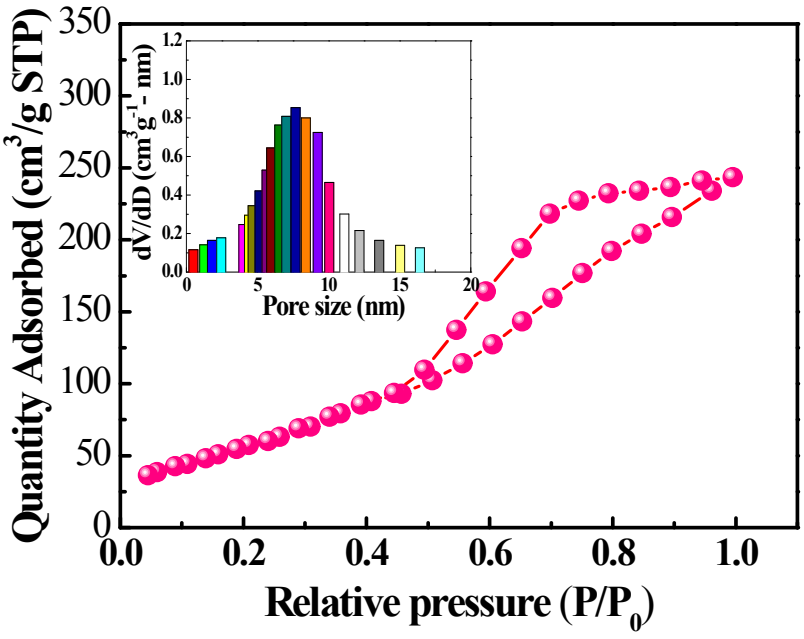

Figure S2. BET measurements of TiC HNSAs (pore distribution in inset).

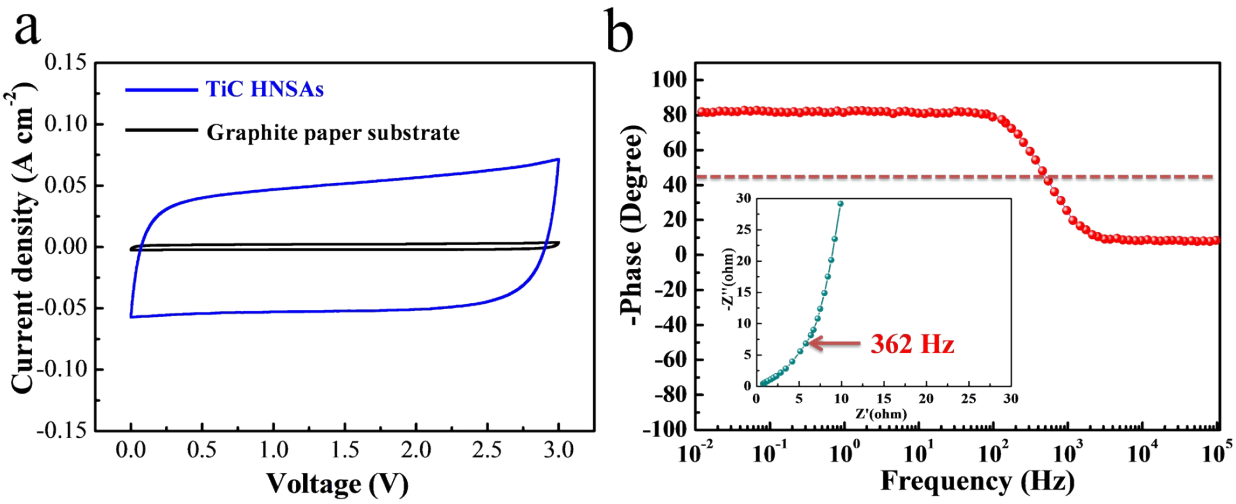

Fig. S3. (a) CV comparison between TiC HNSAs and graphite paper substrate at scan rate of 500 mV s^{-1} at 65 ^{o}C. (b) Bode plots (Impedance phase angle *vs.* frequency) for TiC HNSAs at 65 ^{o}C (Nyquist plots in inset)